## NSN 5961-01-377-1123

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View Online at https://aerobasegroup.com/nsn/5961-01-377-1123 **Inclosure Material:** Metal **Overall Length:** Between 0.570 inches and 0.620 inches **Terminal Length:** Between 0.500 inches and 0.562 inches **Overall Height:** Between 0.160 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.405 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Terminal and unthreaded hole **Features Provided:** W/heat sink **Cubic Measure:** 0.047 cubic inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, total rms pascal **Power Rating Per Characteristic:** 500.0 milliwatts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

No

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